2SK0664G

Silicon N-channel MOSFET

For switching circuits

■ Features

- High-speed switching
- S-mini type package, allowing downsizing of the sets and automatic insertion through the tape/magazine packing

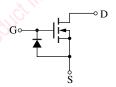
■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Drain-source surrender voltage	V _{DSS}	50	V	
Gate-source voltage (Drain open)	V _{GSO}	8	V	
Drain current	I_D	100	mA	
Peak drain current	I_{DP}	200	mA	
Power dissipation	P_{D}	150	mW	
Channel temperature	T _{ch}	150	°C	
Storage temperature	T _{stg}	-55 to +150	°C	

Package

- Code
 - SMini3-F2
- Marking Symbol: 3N
- Pin Name
 - 1: Gate
 - 2: Source
 - 3: Drain

Internal Connection



■ Electrical Characteristics T_a = 25°C ± 3°C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Drain-source surrender voltage	V_{DSS}	$I_D = 100 \mu\text{A}, V_{GS} = 0$	50			V
Drain-source cutoff current	I_{DSS}	$V_{DS} = 10 \text{ V}, V_{GS} = 0$			10	μΑ
Gate-source cutoff current	I_{GSS}	$V_{GS} = 8 \text{ V}, V_{DS} = 0$			50	nA
Gate threshold voltage	V _{th}	$I_D = 100 \mu\text{A}, V_{DS} = V_{GS}$	1.5		3.5	V
Forward transfer admittance	Y _{fs}	$I_D = 20 \text{ mA}, V_{DS} = 5 \text{ V}, f = 1 \text{ kHz}$	20			mS
Drain-source ON resistance	R _{DS(on)}	$I_D = 20 \text{ mA}, V_{GS} = 5 \text{ V}$			50	Ω
Short-circuit forward transfer capacitance (Common source)	C _{iss}	$V_{DS} = 5 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$			15	pF
Short-circuit output capacitance (Common source)	C _{oss}				5.0	pF
Reverse transfer capacitance (Common source)	C _{rss}				1.0	pF
Turn-on time *1, 2	t _{on}	$V_{DD} = 5 \text{ V}, V_{GS} = 0 \text{ V} \sim 5 \text{ V}, R_L = 200 \Omega$		10		ns
Turn-off time *1, 2	t _{off}	$V_{DD} = 5 \text{ V}, V_{GS} = 5 \text{ V} \sim 0 \text{ V}, R_L = 200 \Omega$		20		ns

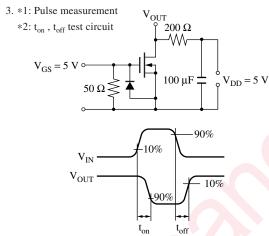
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

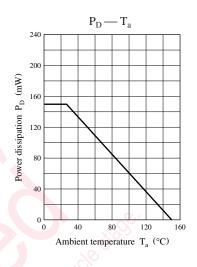
Note) The part number in the parenthesis shows conventional part number.

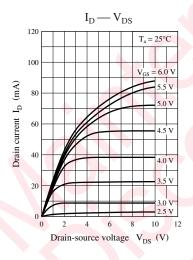
^{2.} Observe precautions for handling. Electrostatic sensitive devices.

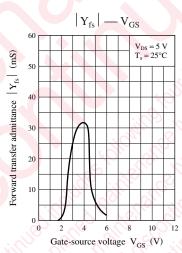
■ Electrical Characteristics (continude)

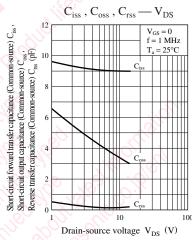
Note) (continude)

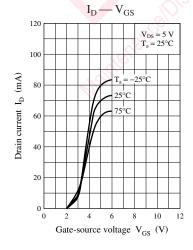


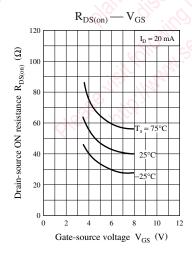


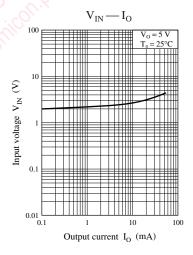




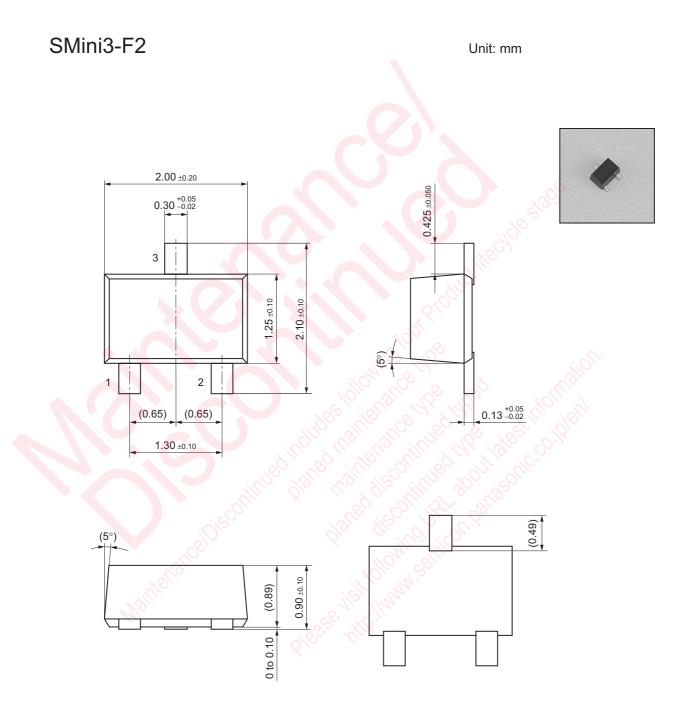








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